

IFW

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q88663

Tsuyoshi NAKANO, et al.

Appln. No.: 10/540,515

Group Art Unit: 2813

Confirmation No.: 6621

Examiner: Monica D. Harrison

Filed: June 23, 2005

For:

COMPOUND SEMICONDUCTOR EPITAXIAL SUBSTRATE AND METHOD FOR

MANUFACTURING THE SAME

AMENDMENT UNDER 37 C.F.R. § 1.111

MAIL STOP AMENDMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the Office Action dated December 13, 2006, please amend the aboveidentified application as follows on the accompanying pages.

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